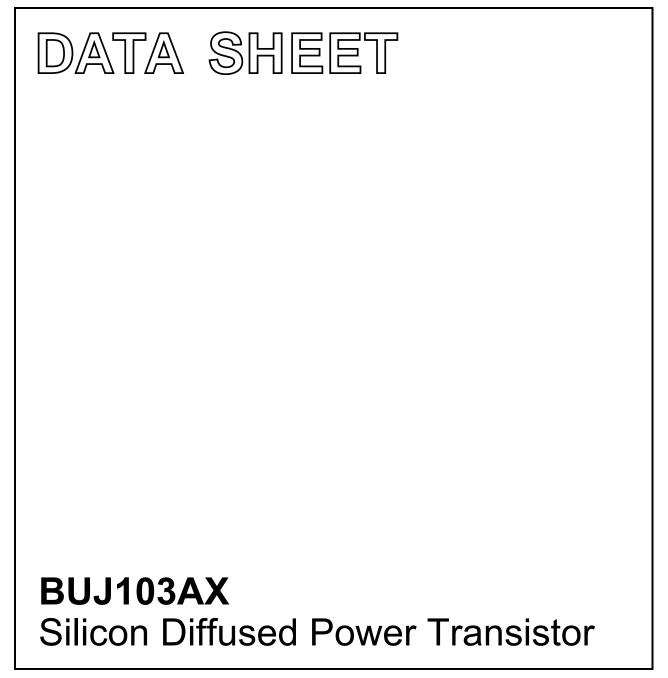
DISCRETE SEMICONDUCTORS



Product specification

August 2018



BUJ103AX

GENERAL DESCRIPTION

High-voltage, high-speed planar-passivated npn power switching transistor in a plastic full-pack envelope intended for use in high frequency electronic lighting ballast applications, converters, inverters, switching regulators, motor control systems, etc.

QUICK REFERENCE DATA

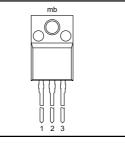
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 V$	-	700	V
V _{CBO}	Collector-Base voltage (open emitter)		-	700	V
V _{CEO}	Collector-emitter voltage (open base)		-	400	V
	Collector current (DC)		-	4	Α
1 17	Collector current peak value		-	8	Α
P _{tot}	Total power dissipation	$T_{hs} \le 25 \degree C$	-	26	W
P _{tot} V _{CEsat}	Collector-emitter saturation voltage		0.25	1.0	V
h _{FEsat}	DC current gain	$I_{c} = 3 \text{ A}; V_{cf} = 5 \text{ V}$	12.5	-	
t _f	Fall time	I _c = 3 A; V _{ce} = 5 V Ic=2A,I _{B1} =0.4A	33	80	ns

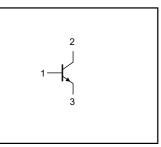
PINNING - SOT186A

PIN CONFIGURATION

SYMBOL

PIN	DESCRIPTION	
1	base	
2	collector	
3	emitter	
mb	solated	





LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CESM}	Collector to emitter voltage	$V_{BE} = 0 V$	-	700	V
V _{CEO}	Collector to emitter voltage (open base)		-	400	V
V _{CEO} V _{CBO}	Collector to base voltage (open emitter)		-	700	V
I _C	Collector current (DC)		-	4	Α
I _{CM}	Collector current peak value		-	8	Α
I _B	Base current (DC)		-	2	Α
1 1	Base current peak value		-	4	Α
	Total power dissipation	T _{hs} ≤ 25 °C	-	26	W
T _{stg}	Storage temperature	113	-65	150	°C
T _j	Junction temperature		-	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-hs}	Junction to heatsink	with heatsink compound	-	4.8	K/W
R _{th j-a}	Junction to ambient	in free air	55	-	K/W

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ISOLATION LIMITING VALUE & CHARACTERISTIC

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. $\leq 65\%$; clean and dustfree	-		2500	~
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	10	-	pF

STATIC CHARACTERISTICS

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CES} I _{CES}	Collector cut-off current ¹		-	-	1.0 2.0	mA mA
I _{CBO} I _{CEO}	Collector cut-off current ¹	$\begin{array}{l} V_{\text{CBO}} = V_{\text{CESMmax}}(700\text{V}) \\ V_{\text{CEO}} = V_{\text{CEOMmax}}(400\text{V}) \end{array}$	-	-	0.1 0.1	mA mA
I _{EBO} V _{CEOsust}	Emitter cut-off current Collector-emitter sustaining voltage	$V_{EB} = 7 V; I_{C} = 0 A$ $I_{B} = 0 A; I_{C} = 10 mA;$ L = 25 mH	400	- -	0.1 -	mA V
$\begin{array}{l} V_{\text{CEsat}} \\ V_{\text{BEsat}} \\ h_{\text{FE}} \\ h_{\text{FE}} \\ h_{\text{FEsat}} \end{array}$	Collector-emitter saturation voltage Base-emitter saturation voltage DC current gain DC current gain	$ I_{c} = 3.0 \text{ A}; I_{B} = 0.6 \text{ A} I_{c} = 3.0 \text{ A}; I_{B} = 0.6 \text{ A} I_{c} = 1 \text{ mA}; V_{CE} = 5 \text{ V} I_{c} = 0.5 \text{ A}; V_{CE} = 5 \text{ V} I_{c} = 2 \text{ A}; V_{CE} = 5 \text{ V} I_{c} = 3 \text{ A}; V_{CE} = 5 \text{ V} $	- 10 12 13.5 -	0.25 0.97 17 20 16 12.5	1.0 1.5 32 32 20	V V

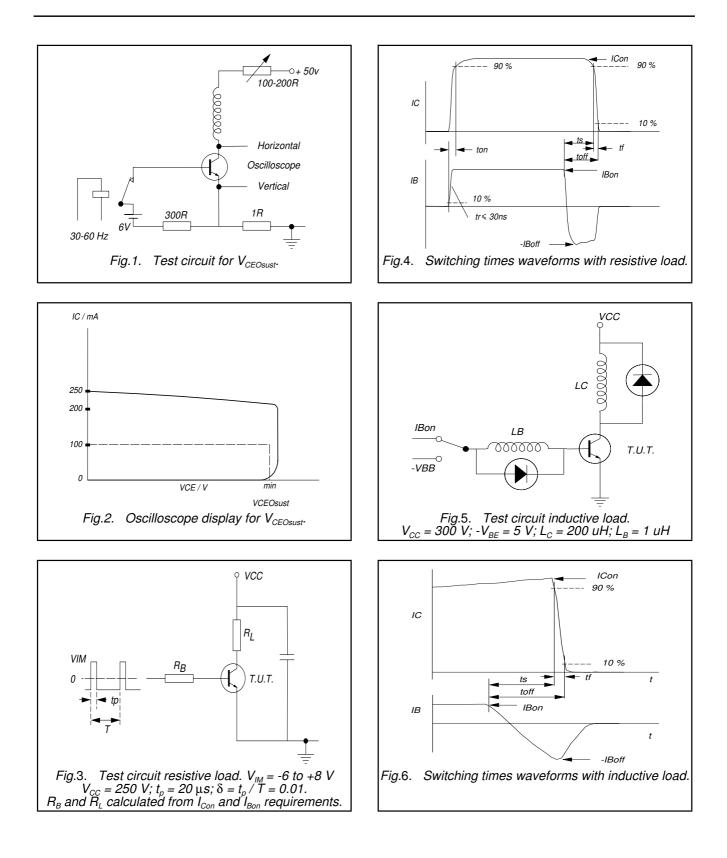
DYNAMIC CHARACTERISTICS

 T_{hs} = 25 °C unless otherwise specified

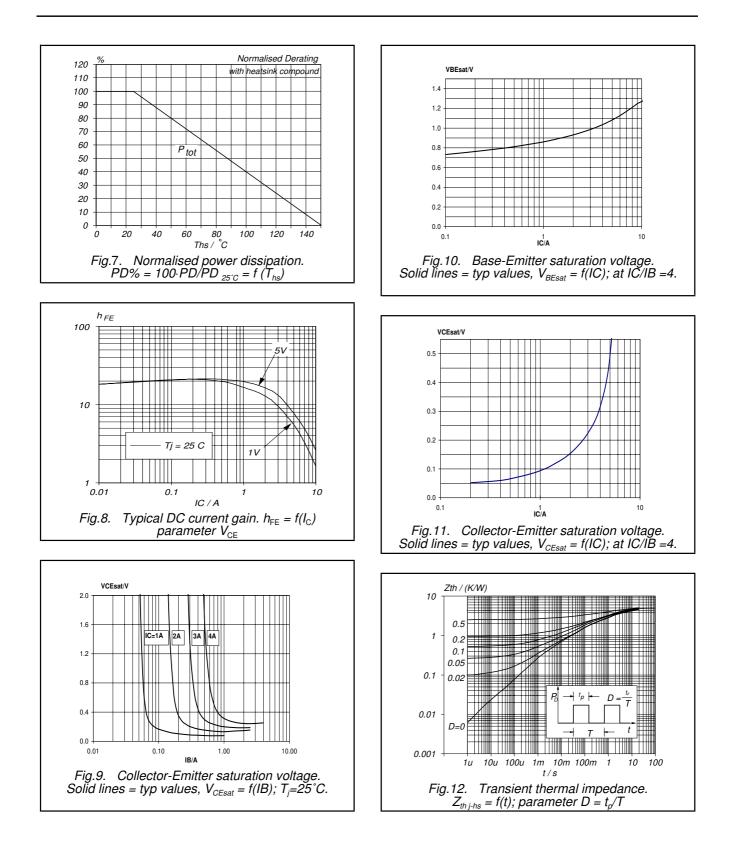
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
	Switching times (resistive load)	$I_{Con} = 2.5 \text{ A}; I_{Bon} = -I_{Boff} = 0.5 \text{ A};$ R ₁ = 75 ohms; V _{BB2} = 4 V;			
t _{on} t _s t _f	Turn-on time Turn-off storage time Turn-off fall time		0.52 2.7 0.3	0.6 3.2 0.43	μs μs μs
	Switching times (inductive load)	$I_{Con} = 2 \text{ A}; I_{Bon} = 0.4 \text{ A}; L_{B} = 1 \mu\text{H};$ - $V_{BB} = 5 \text{ V}$			
t _s t _f	Turn-off storage time Turn-off fall time		1.2 33	1.33 80	μs ns
	Switching times (inductive load)	$ I_{Con} = 2 \text{ A}; I_{Bon} = 0.4 \text{ A}; L_{B} = 1 \mu\text{H}; \\ -V_{BB} = 5 \text{ V}; T_{i} = 100 ^{\circ}\text{C} $			
t _s t _f	Turn-off storage time Turn-off fall time		-	1.8 200	μs ns

¹ Measured with half sine-wave voltage (curve tracer).

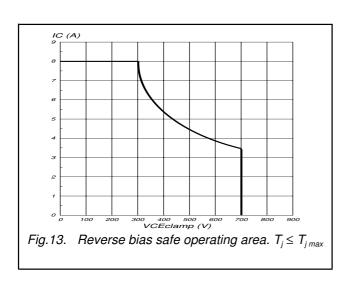
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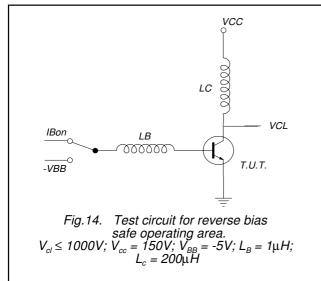


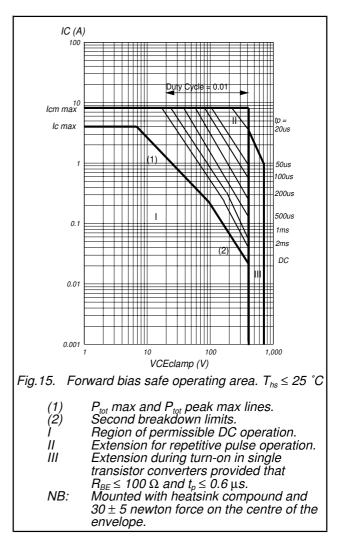
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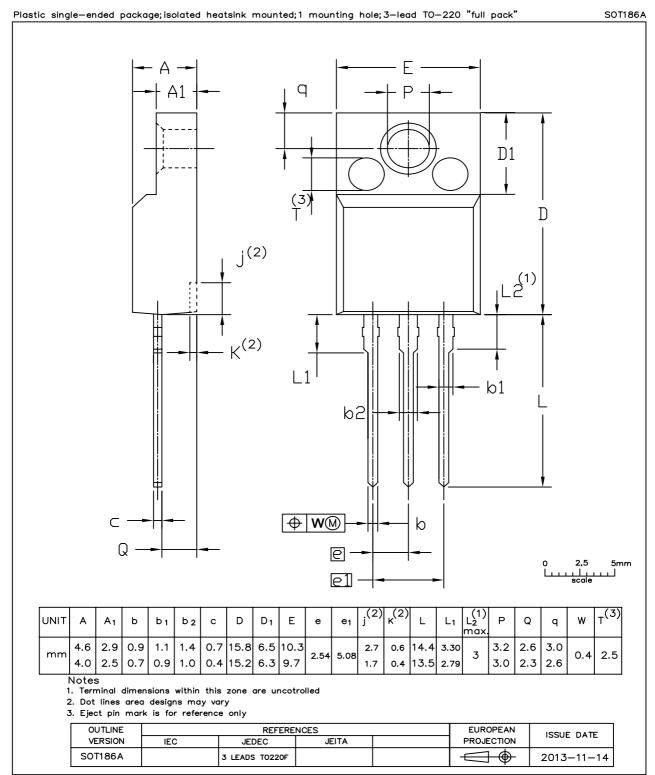






BUJ103AX

MECHANICAL DATA



Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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